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May 2010

#### FDMC86324

# N-Channel Power Trench<sup>®</sup> MOSFET 80 V, 20 A, 23 m $\Omega$

#### **Features**

- Max  $r_{DS(on)} = 23 \text{ m}\Omega$  at  $V_{GS} = 10 \text{ V}$ ,  $I_D = 7 \text{ A}$
- Max  $r_{DS(on)} = 37 \text{ m}\Omega$  at  $V_{GS} = 6 \text{ V}$ ,  $I_D = 4 \text{ A}$
- Low Profile 1 mm max in Power 33
- 100% UIL Tested
- RoHS Compliant



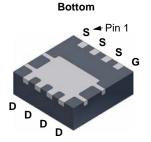
#### **General Description**

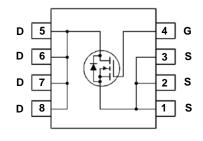
This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench® process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

#### **Application**

■ DC - DC Conversion







Power 33

#### MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol	Parameter	Ratings	Units		
$V_{DS}$	Drain to Source Voltage			80	V
$V_{GS}$	Gate to Source Voltage			±20	V
	Drain Current -Continuous (Package limited)	T <sub>C</sub> = 25 °C		20	
	-Continuous (Silicon limited)	T <sub>C</sub> = 25 °C		30	
ID	-Continuous	T <sub>A</sub> = 25 °C	(Note 1a)	7	A
	-Pulsed			30	
E <sub>AS</sub>	Single Pulse Avalanche Energy		(Note 3)	72	mJ
D	Power Dissipation	T <sub>C</sub> = 25 °C		41	W
$P_{D}$	Power Dissipation	T <sub>A</sub> = 25 °C	(Note 1a)	2.3	VV
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature R	ange		-55 to +150	°C

#### **Thermal Characteristics**

$R_{\theta JC}$	Thermal Resistance, Junction to Case		3	°C/W
R <sub>e.IA</sub>	Thermal Resistance, Junction to Ambient	(Note 1a)	53	C/VV

#### **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC86324	FDMC86324	Power 33	13"	12 mm	3000 units

## **Electrical Characteristics** $T_J = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	80			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D$ = 250 $\mu$ A, referenced to 25 °C		69		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 64 V, V <sub>GS</sub> = 0 V			1	μΑ
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA

#### On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2.0	3.1	4.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D$ = 250 $\mu$ A, referenced to 25 °C		-9		mV/°C
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 7 A		19.1	23	
r <sub>DS(on)</sub>	r <sub>DS(on)</sub> Static Drain to Source On Resistance	$V_{GS} = 6 \text{ V}, I_D = 4 \text{ A}$		25.5	37	mΩ
		$V_{GS} = 10 \text{ V}, I_D = 7 \text{ A}, T_J = 125 ^{\circ}\text{C}$		32.5	40	
g <sub>FS</sub>	Forward Transconductance	V <sub>DD</sub> = 10 V, I <sub>D</sub> = 7 A		19		S

#### **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance			725	965	pF
C <sub>oss</sub>	Output Capacitance	$V_{DS} = 50 \text{ V}, V_{GS} = 0 \text{ V},$ 		175	235	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	1 - 1 1/11/12		15	25	pF
$R_g$	Gate Resistance			0.5		Ω

#### **Switching Characteristics**

t <sub>d(on)</sub>	Turn-On Delay Time			8	17	ns
t <sub>r</sub>	Rise Time	$V_{DD} = 50 \text{ V, } I_{D} = 7 \text{ A,}$		4	10	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS}$ = 10 V, $R_{GEN}$ = 6 $\Omega$		14	25	ns
t <sub>f</sub>	Fall Time			4	10	ns
0	Total Gate Charge	V <sub>GS</sub> = 0 V to 10 V		13	18	nC
$Q_{g(TOT)}$	Total Gate Charge	$V_{GS} = 0 \text{ V to 5 V}$ $V_{DD} = 50$	V	8	11	nC
$Q_{gs}$	Total Gate Charge	I <sub>D</sub> = 7 A		3.7		nC
$Q_{gd}$	Gate to Drain "Miller" Charge			3.6		nC

#### **Drain-Source Diode Characteristics**

V C.	Ven Source to Drain Dioge Forward Voltage	$V_{GS} = 0 \text{ V}, I_S = 7 \text{ A}$ (Note	2)	0.81	1.3	\/
V SD		$V_{GS} = 0 \text{ V}, I_S = 2 \text{ A}$ (Note	2)	0.75	1.2	V
t <sub>rr</sub>	Reverse Recovery Time	- I <sub>F</sub> = 7 A, di/dt = 100 A/μs		44	70	ns
Q <sub>rr</sub>	Reverse Recovery Charge			40	65	nC

#### NOTES

1. R<sub>0,JA</sub> is determined with the device mounted on a 1in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R<sub>0,JC</sub> is guaranteed by design while R<sub>0,CA</sub> is determined by the user's board design.



a. 53 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper



b. 125 °C/W when mounted on a minimum pad of 2 oz copper

- 2. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty cycle < 2.0 %.
- 3. Starting  $T_J$  = 25 °C; N-ch: L = 1 mH,  $I_{AS}$  = 12 A,  $V_{DD}$  = 72 V,  $V_{GS}$  = 10 V.

#### Typical Characteristics T<sub>J</sub> = 25 °C unless otherwise noted

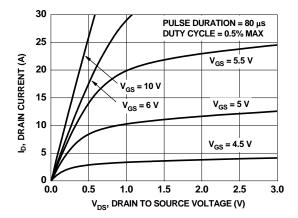


Figure 1. On-Region Characteristics

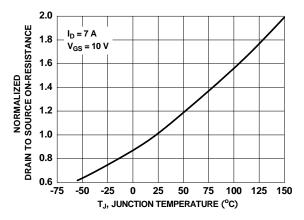


Figure 3. Normalized On-Resistance vs Junction Temperature

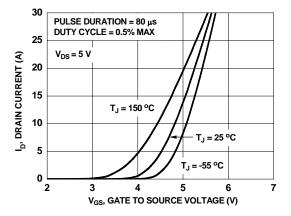


Figure 5. Transfer Characteristics

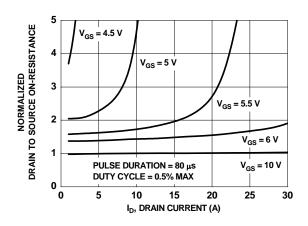


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

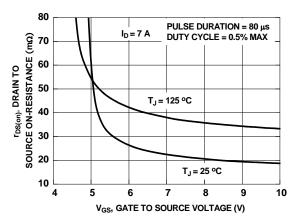


Figure 4. On-Resistance vs Gate to Source Voltage

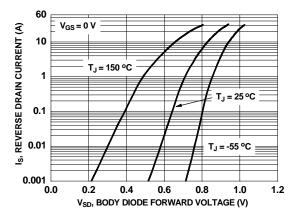


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

#### **Typical Characteristics** $T_J = 25$ °C unless otherwise noted

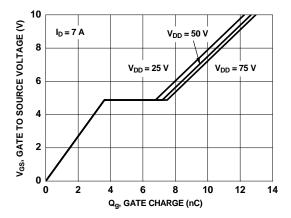


Figure 7. Gate Charge Characteristics

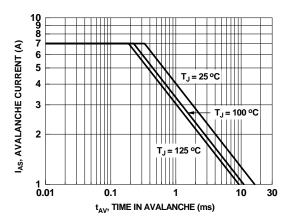


Figure 9. Unclamped Inductive Switching Capability

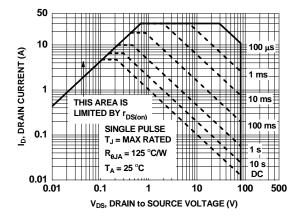


Figure 11. Forward Bias Safe Operating Area

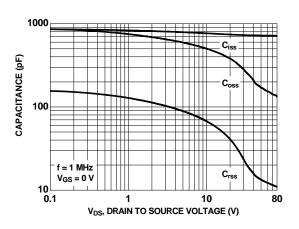


Figure 8. Capacitance vs Drain to Source Voltage

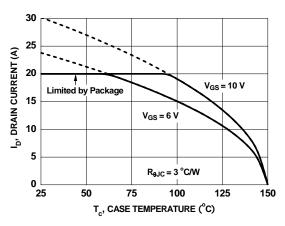


Figure 10. Maximum Continuous Drain Current vs Case Temperature

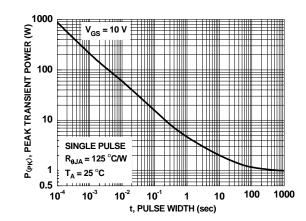


Figure 12. Single Pulse Maximum Power Dissipation

## **Typical Characteristics** $T_J = 25$ °C unless otherwise noted

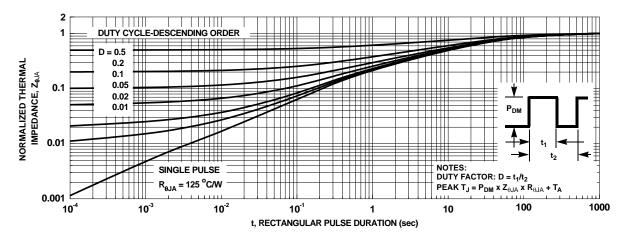
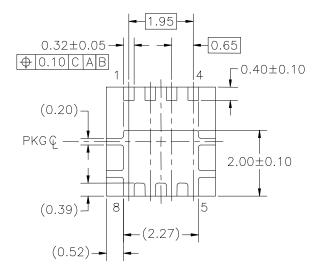
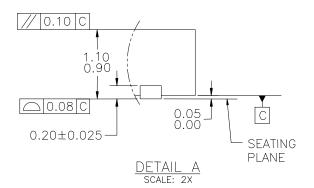


Figure 13. Junction-to-Ambient Transient Thermal Response Curve

#### **Dimensional Outline and Pad Layout** -3.30±0.10-2.37 MIN SYM PKG -(0.45) 8 5 2.15 MIN (0.40)PKG PKGQ $3.30\pm0.10$ (0.65) $\bigcirc$ 0.70 MIN 0.65--0.42 MIN SEE DETAIL A LAND PATTERN





PQFN08BREV1

NOTES: UNLESS OTHERWISE SPECIFIED

A) PACKAGE STANDARD REFERENCE: JEDEC MO-240, ISSUE A, VAR. BA, DATED OCTOBER 2002.

RECOMMENDATION

- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS DO NOT INCLUDE BURRS OR MOLD FLASH. MOLD FLASH OR BURRS DOES NOT EXCEED 0.10MM.
- D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- E) DRAWING FILE NAME: PQFN08BREV1





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